

New progress in quantum anomalous Hall effect

Qi-Kun Xue

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Acknowledgements

Tsinghua: MBE, STM and ARPES

Yunbo Ou, Gaoyuan Jiang, Xiao Feng, Li-Guo Zhang, Li-Li Wang, Wei Li, Can-Li Song, Ding Zhang, Ke He, Xu-Cun Ma

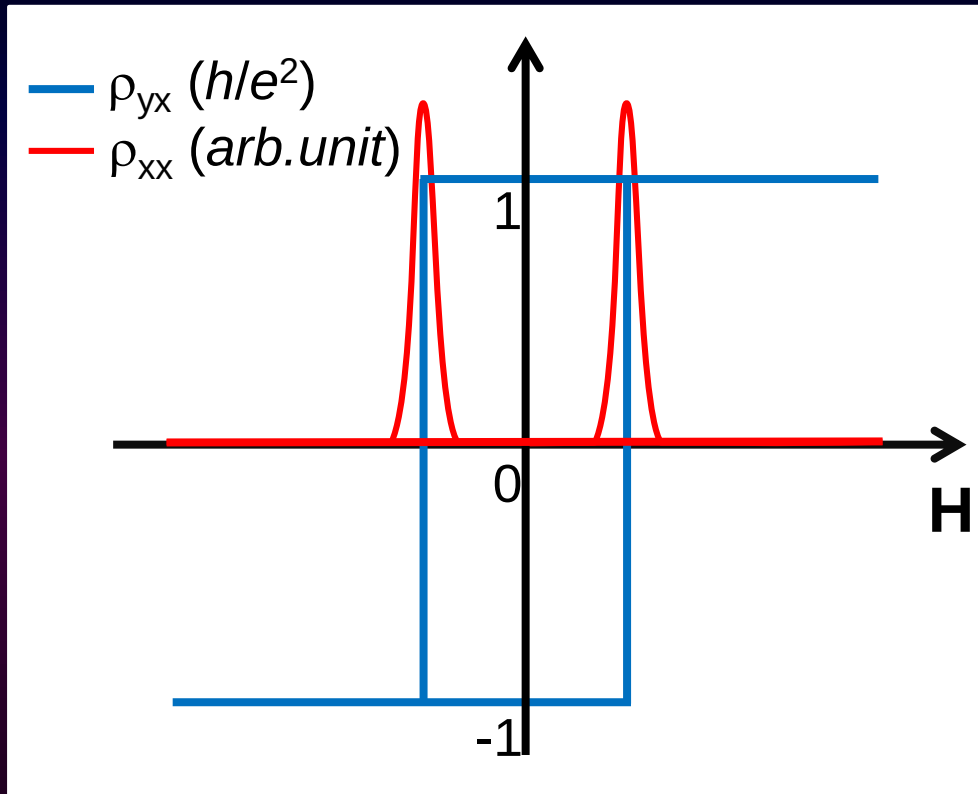
Tsinghua: Transport

Yang Feng, Weixiong Wu, Chang Liu, Shaorui Li, Yaoxin Li, and Yayu Wang

Rutgers: MFM Wenbo Wang, Weida Wu

IOP, CAS: TEM Qinghua Zhang, Xiaozhi Liu, Lin Gu

Quantum Anomalous Hall Effect (QAHE)

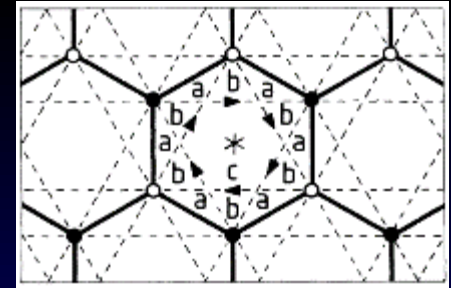


$$\rho_{yx}(H = 0) = h / ie^2$$

$$\rho_{xx}(H = 0) = 0$$

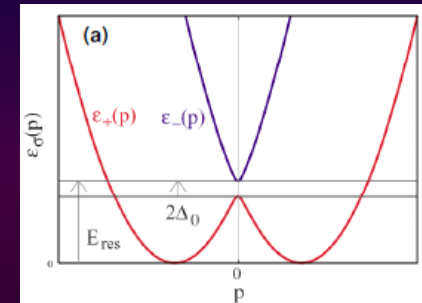
TRS-broken graphene

Haldane, PRL 1988



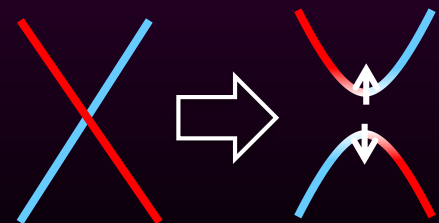
2D FM system with SOC

Onoda & Nagaosa, PRL 2003



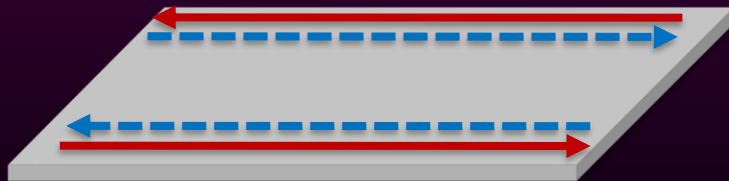
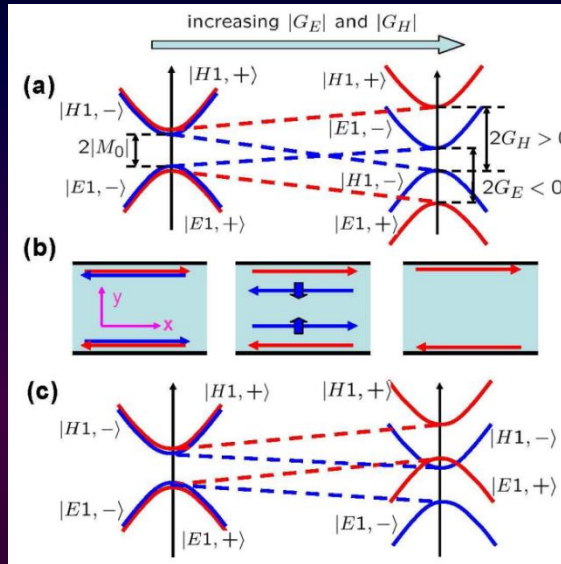
Magnetic topological insulator

SC Zhang et al., since 2006



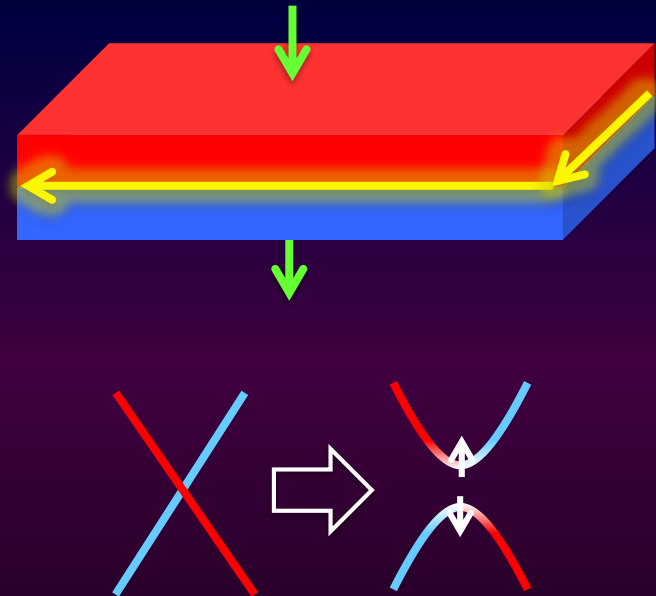
QAHE in magnetic TIs

2D TI + FM



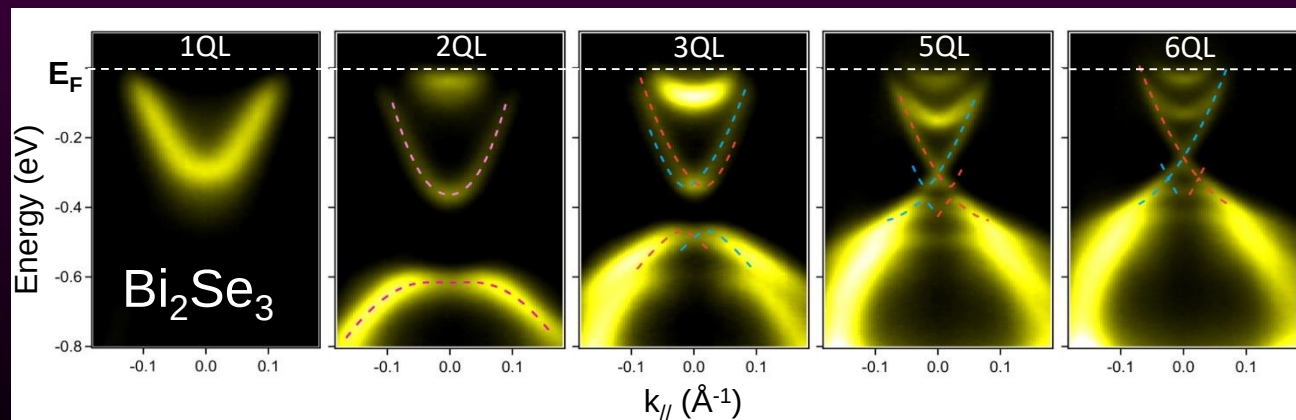
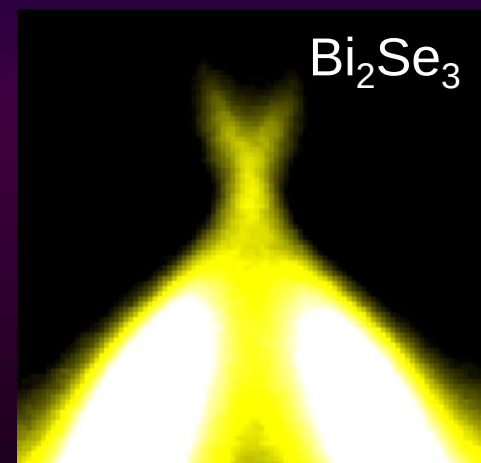
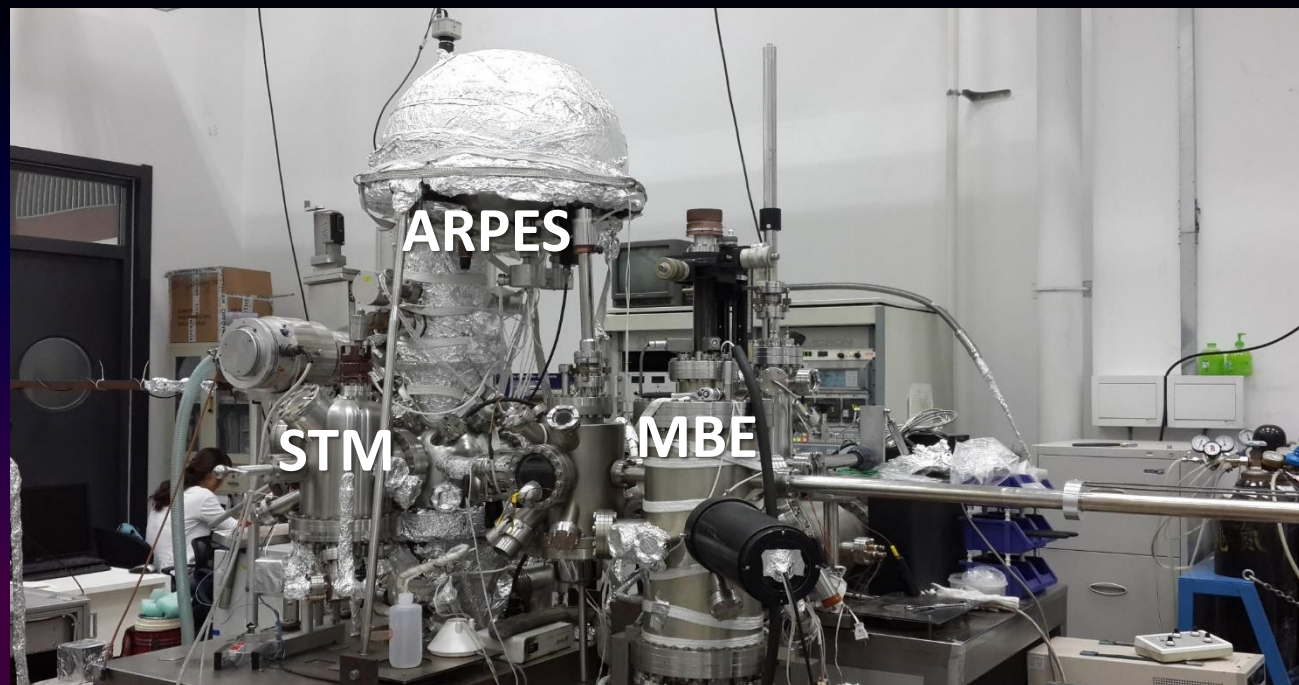
Qi, Wu & Zhang., PRB 2006
C. -X. Liu et al., PRL 2008

3D TI + FM



Qi, Hughes & Zhang PRB 2008
Yu et al., Science 2010

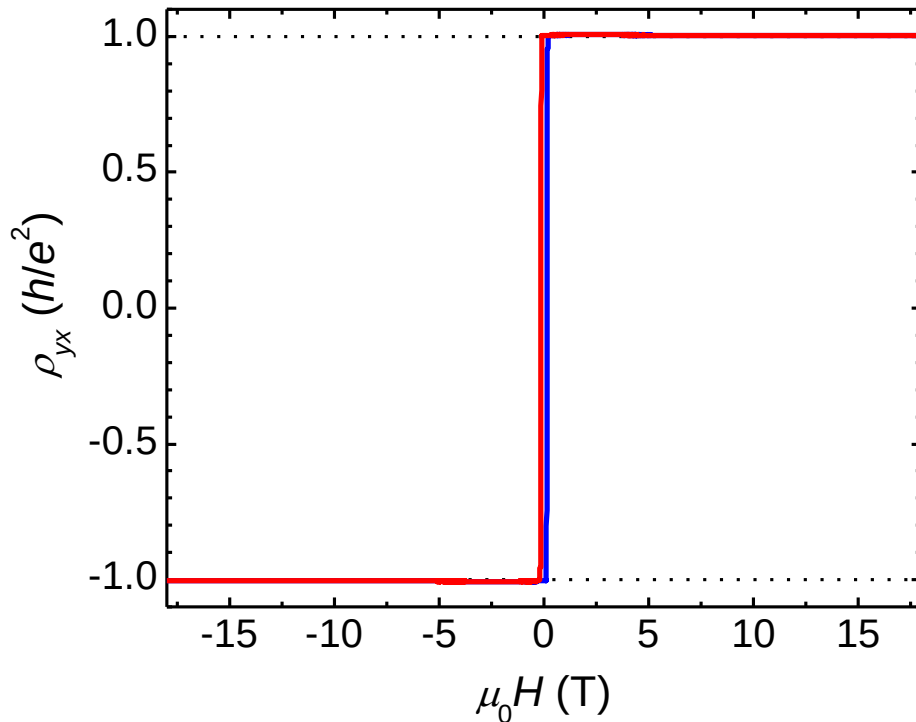
MBE + STM + ARPES for TI studies



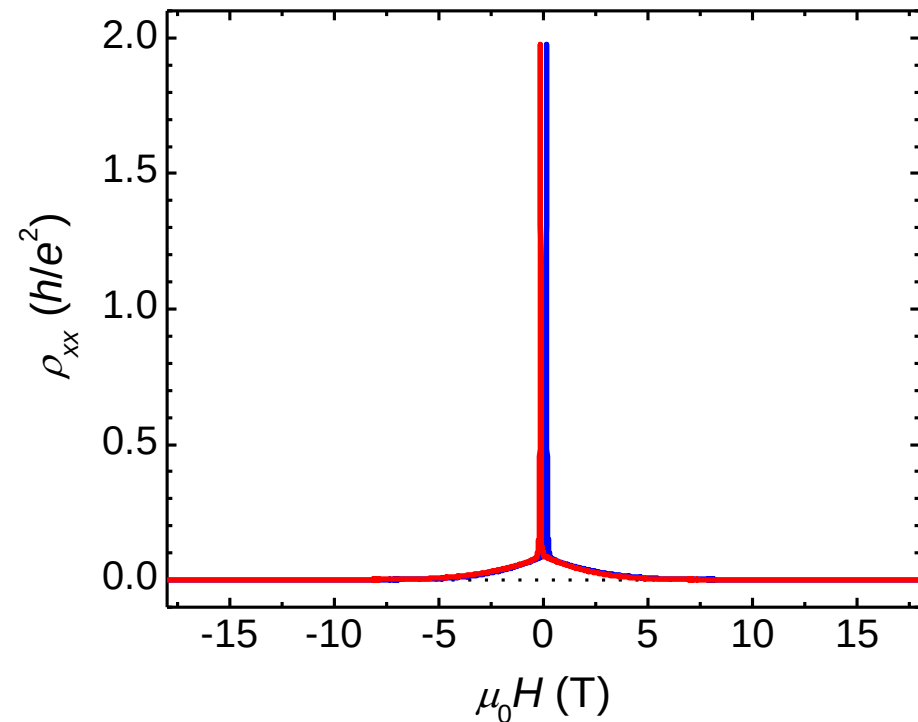
Adv. Mater. 22, 4002 (2010)
Nat. Phys. 6, 584 (2010)

QAHE observed in Cr-doped $(\text{Bi,Sb})_2\text{Te}_3$

@ 30 mK



with Li Lv (IOP)



C. -Z. Chang et al., Science 340, 167 (2013)

Confirmation of QAHE

nature
physics

LETTERS

PUBLISHED ONLINE: 17 AUGUST 2014 | DOI: 10.1038/NPHYS3053

Trajectory of the anomalous Hall effect towards the quantized state in a ferromagnetic topological insulator

J. G. Checkelsky^{1*}, R. Yoshimi¹, A. Tsukazaki², K. S. Takahashi³, Y. Kozuka¹, J. Falson¹, M. Kawasaki^{1,3} and Y. Tokura^{1,3}

2014.09: UCLA

nature
materials

LETTERS

PUBLISHED ONLINE: 2 MARCH 2015 | DOI: 10.1038/NMAT4204

High-precision realization of robust quantum anomalous Hall state in a hard ferromagnetic topological insulator

Cui-Zu Chang^{1*}, Weiwei Zhao^{2*}, Duk Y. Kim³, Haijun Zhang³, Badih A. Assaf⁴, Don Heiman⁴, Shou-Cheng Zhang³, Chaoxing Liu², Moses H. W. Chan² and Jagadeesh S. Moodera^{1,5*}

2015.05: Stanford

QUANTUM MECHANICS

Large discrete jumps observed in the transition between Chern states in a ferromagnetic topological insulator

Minhao Liu¹, Wudi Wang¹, Anthony R. Richardella², Abhinav Kandala², Jian Li¹, Ali Yazdani¹, Nitin Samarth², N. Phuan Ong^{1*}

2017.06: Wurzburg

2014.08: Tokyo/RIKEM

PRL 113, 137201 (2014)

PHYSICAL REVIEW LETTERS

week ending
26 SEPTEMBER 2014

Scale-Invariant Quantum Anomalous Hall Effect in Magnetic Topological Insulators beyond the Two-Dimensional Limit

Xufeng Kou¹, Shih-Ting Guo², Yabin Fan¹, Lei Pan¹, Murong Lang¹, Ying Jiang³, Qiming Shao¹, Tianxiao Nie¹, Koichi Murata¹, Jianshi Tang¹, Yong Wang³, Liang He¹, Ting-Kuo Lee², Wei-Li Lee^{2,*} and Kang L. Wang^{1,†}

2015.03: MIT

PRL 114, 187201 (2015)

 Selected for a Viewpoint in *Physics*
PHYSICAL REVIEW LETTERS

week ending
8 MAY 2015



Precise Quantization of the Anomalous Hall Effect near Zero Magnetic Field

A. J. Bestwick^{1,2}, E. J. Fox^{1,2}, Xufeng Kou³, Lei Pan³, Kang L. Wang³ and D. Goldhaber-Gordon^{1,2,*}

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under a
NonCom
10.1126/

2016.06: Princeton

PRL 118, 246801 (2017)

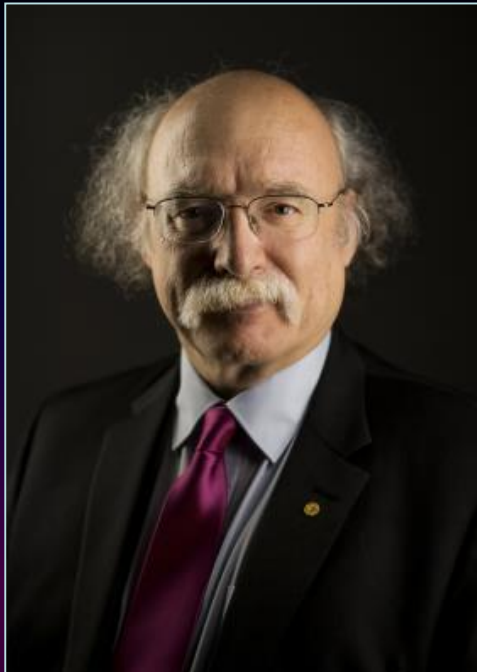
PHYSICAL REVIEW LETTERS

week ending
16 JUNE 2017



Scaling of the Quantum Anomalous Hall Effect as an Indicator of Axion Electrodynamics

Nobel Lecture by F. D. M. Haldane



REVIEWS OF MODERN PHYSICS, VOLUME 89, OCTOBER–DECEMBER 2017

Nobel Lecture: Topological quantum matter^{*}

F. Duncan M. Haldane

Department of Physics, Princeton University, Princeton, New Jersey 08544-0708, USA

(published 9 October 2017)

Nobel Lecture, presented December 8, 2016, Aula Magna, Stockholm University. I will describe the history and background of three discoveries cited in this Nobel Prize: The “TKNN” topological formula for the integer quantum Hall effect found by David Thouless and collaborators, the Chern insulator or quantum anomalous Hall effect, and its role in the later discovery of time-reversal-invariant topological insulators, and the unexpected topological spin-liquid state of the spin-1 quantum antiferromagnetic chain, which provided an initial example of topological quantum matter. I will summarize how these early beginnings have led to the exciting, and currently extremely active, field of “topological matter.”

DOI: 10.1103/RevModPhys.89.040502

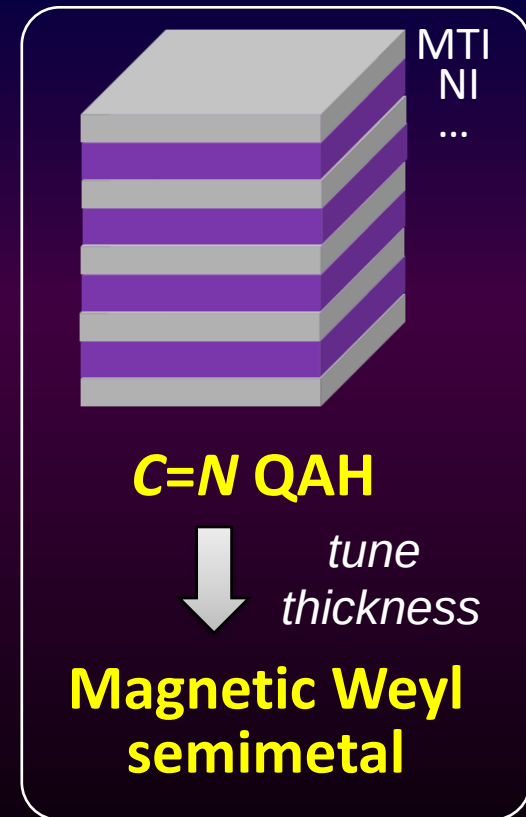
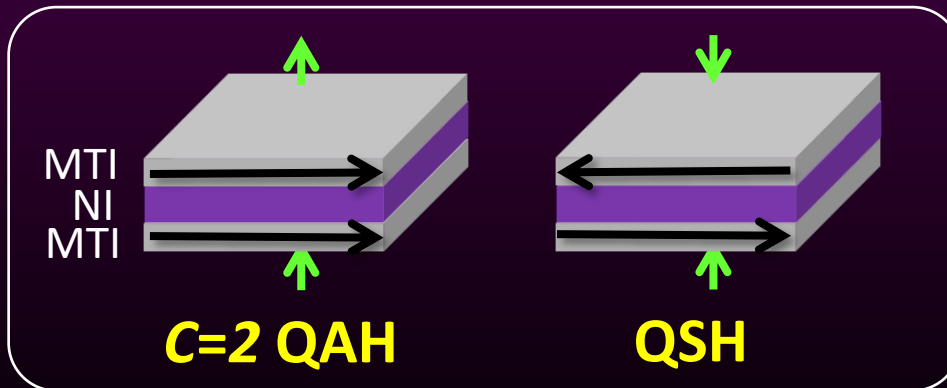
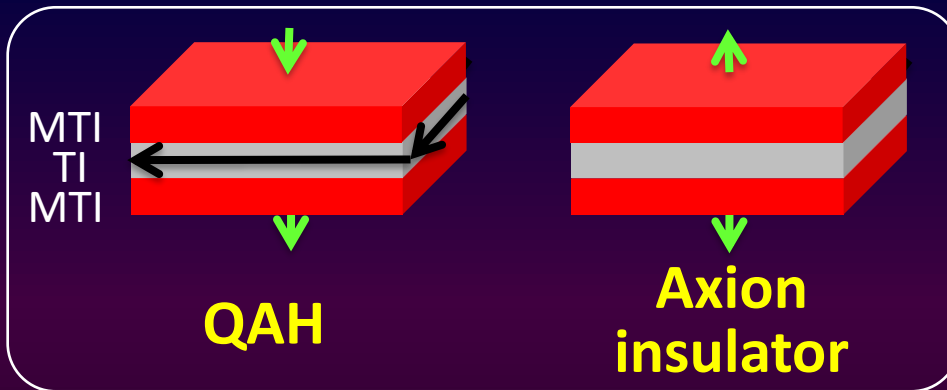
QAHE is among the most important physics effects discovered in topological insulators.

discovery of the 3D time-reversal-invariant topological insulators (TI). This finally led to the reported experimental realization (Chang *et al.*, 2013) by QiKun Xue’s group at Tsinghua University, Beijing, of the quantum anomalous Hall effect in thin films of TRI TI’s which had been doped with magnetic material.

I now turn to the other (1981) discovery recognized by this Nobel prize: the novel quantum spin-liquid states of the one-

Recent progresses in QAHE

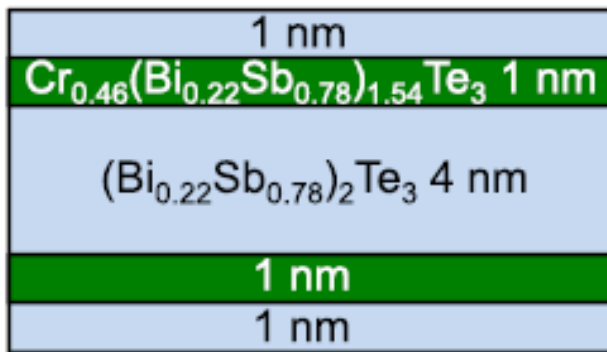
- Higher temperature: **Cr+V co-doped $(\text{Bi,Sb})_2\text{Te}_3$**
- Other novel topological states of matter



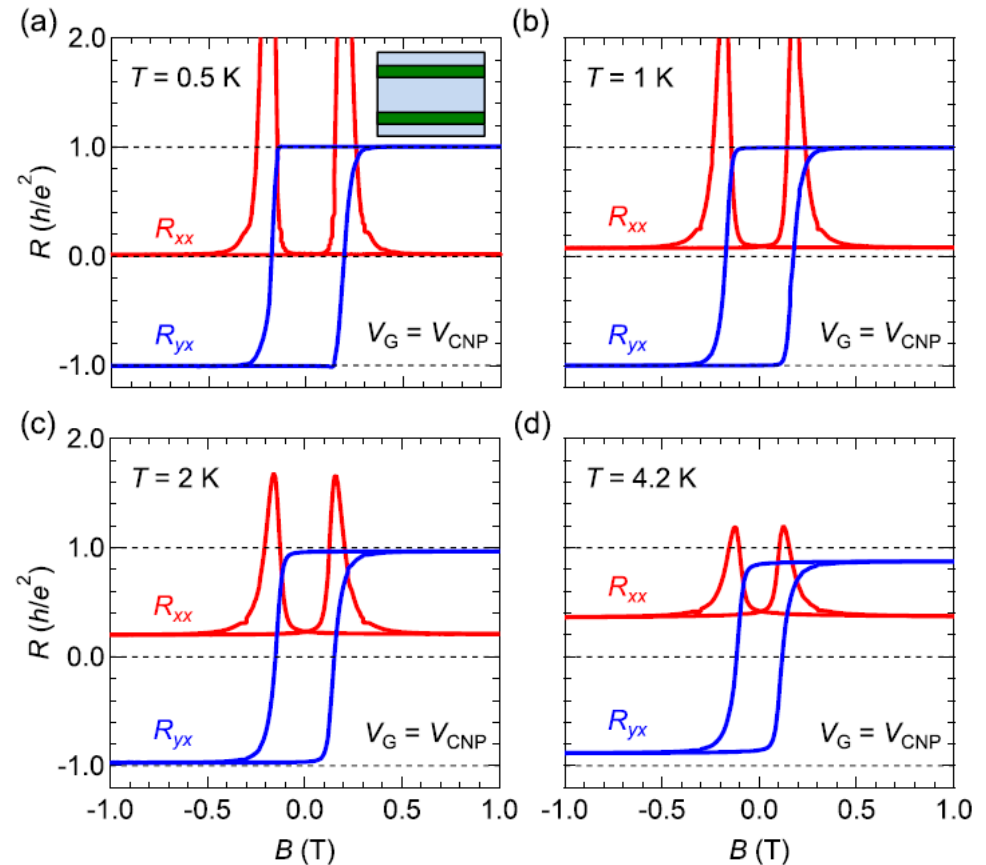
“Penta-layer” Cr-doped $(\text{Bi,Sb})_2\text{Te}_3$

Y. Tokura: APL 107, 182401 (2015)

(c) penta-layer



Good quantization
at 0.5 K and zero field



Quantized Anomalous Hall Effect in V-Sb₂Te₃

nature
materials

LETTERS

PUBLISHED ONLINE: 2 MARCH 2015 | DOI: 10.1038/NMAT4204

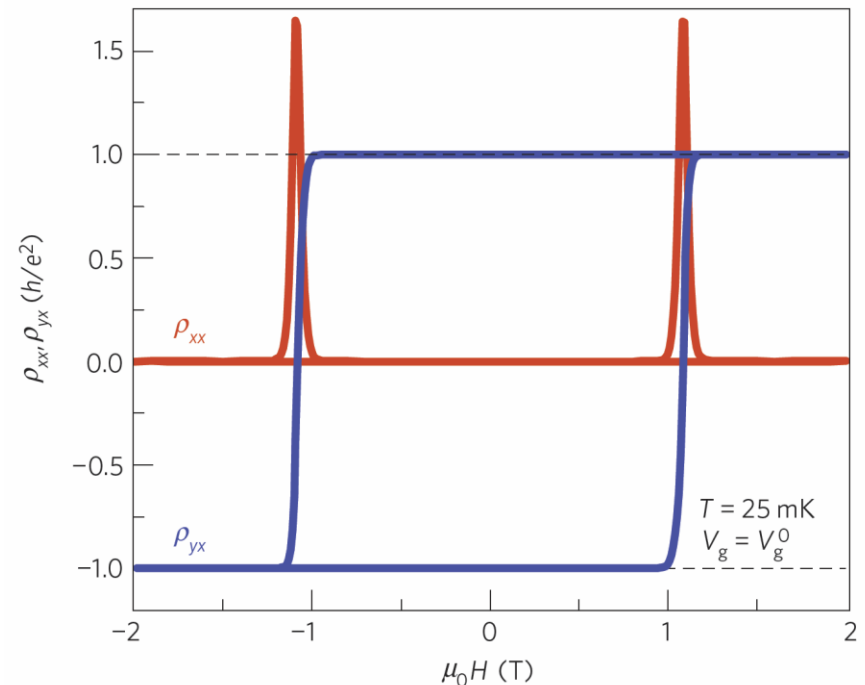
High-precision realization of robust quantum anomalous Hall state in a hard ferromagnetic topological insulator

MIT/PSU/Stanford

Cui-Zu Chang^{1*}, Weiwei Zhao^{2*}, Duk Y. Kim², Haijun Zhang³, Badi H. Assaf⁴, Don Heiman⁴, Shou-Cheng Zhang³, Chaoxing Liu², Moses H. W. Chan² and Jagadeesh S. Moodera^{1,5*}

V-doped Sb₂Te₃
(~4%)

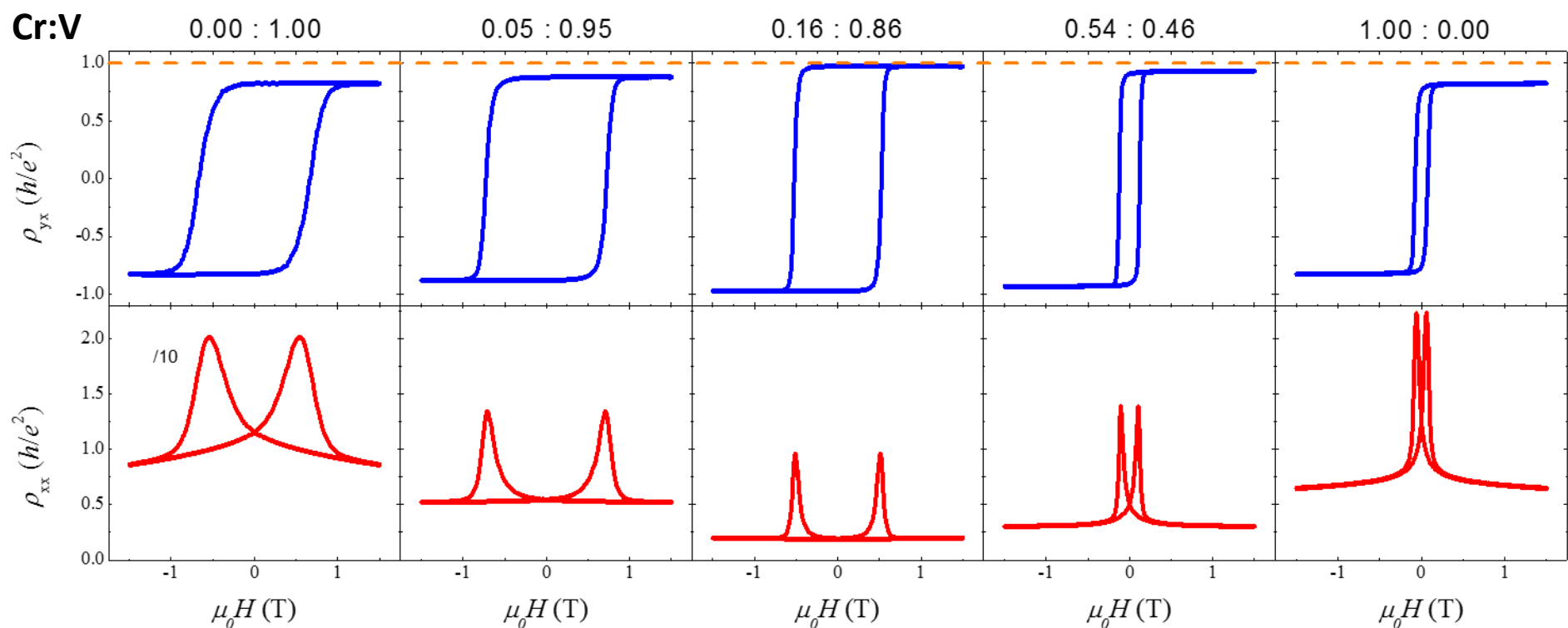
Dr. Chang and Prof. Moodera (MIT)



Higher QAHE temperature in Cr & V co-doped $(\text{Bi,Sb})_2\text{Te}_3$ films

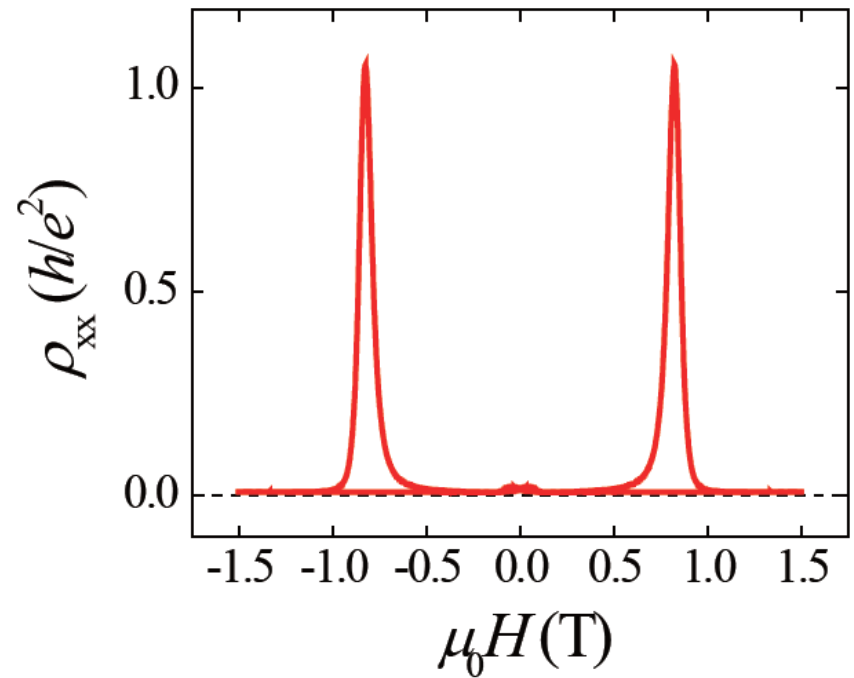
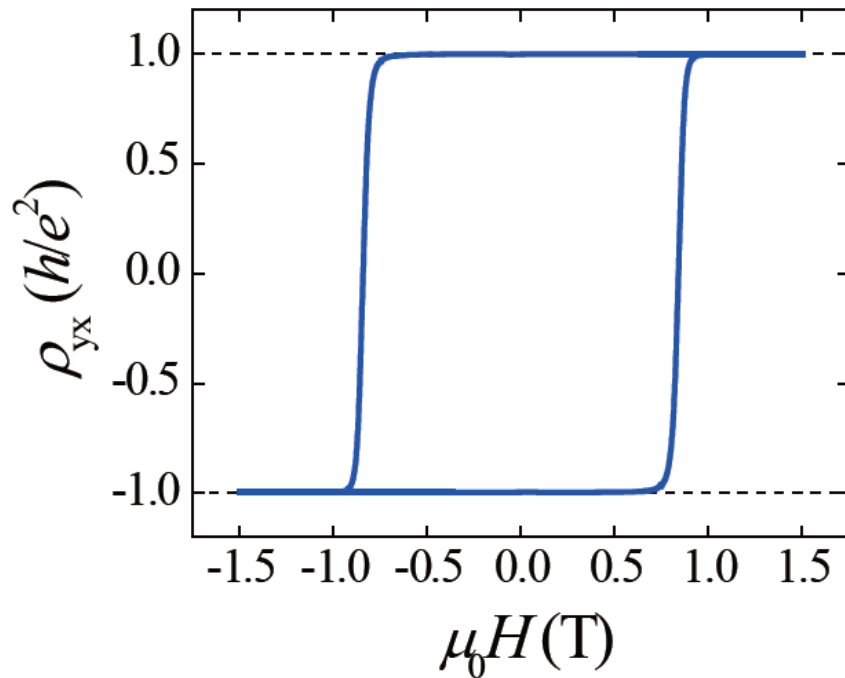
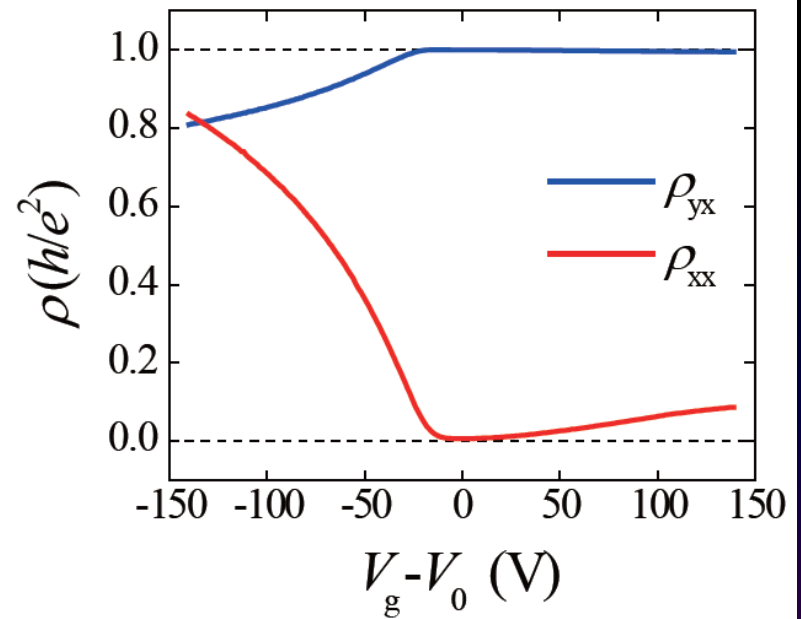
5 QL $(\text{Cr}_y\text{V}_{1-y})_{0.19}(\text{Bi}_x\text{Sb}_{1-x})_{1.81}\text{Te}_3$

$0.97 h/e^2$ @ 1.5 K

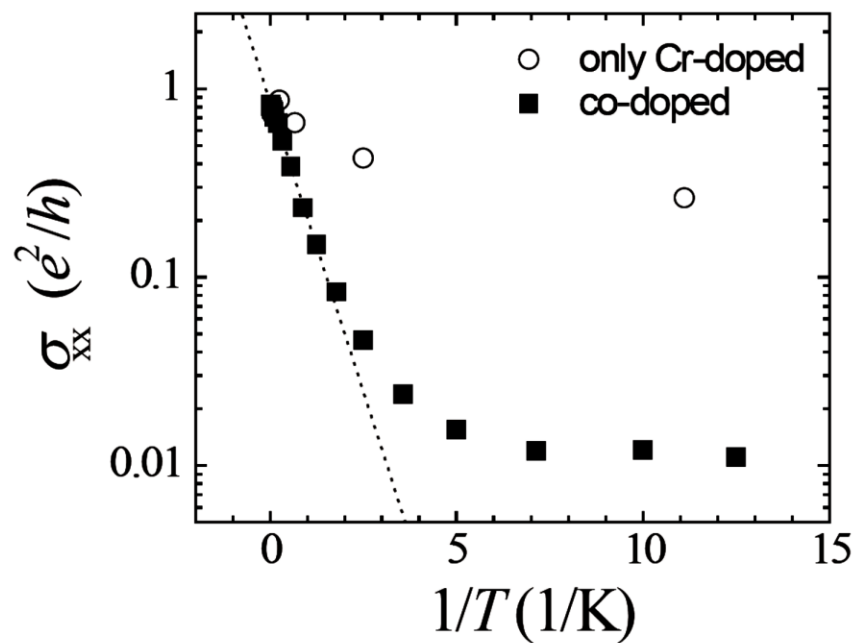
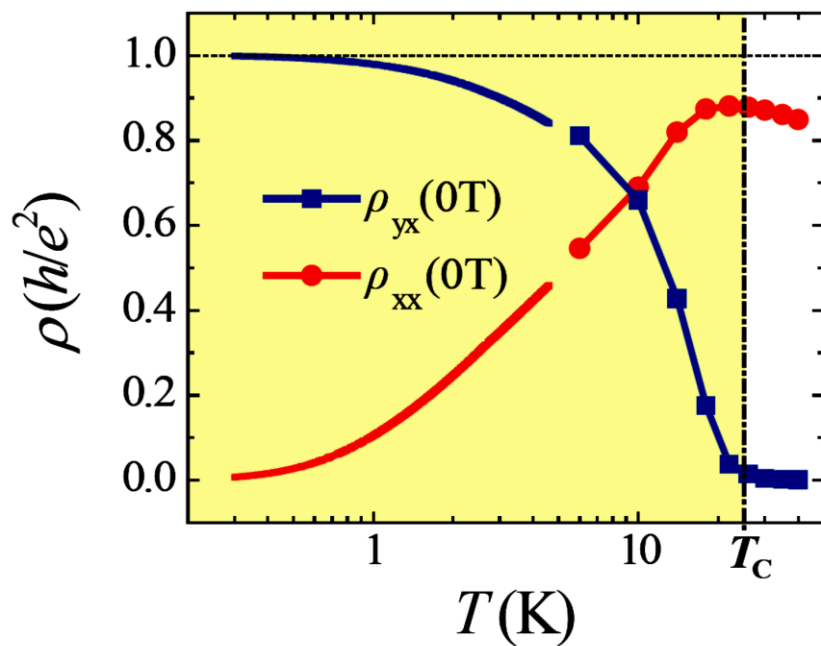


Full quantization at 0.3 K

Y. Ou et al., Adv. Mater. (2018)

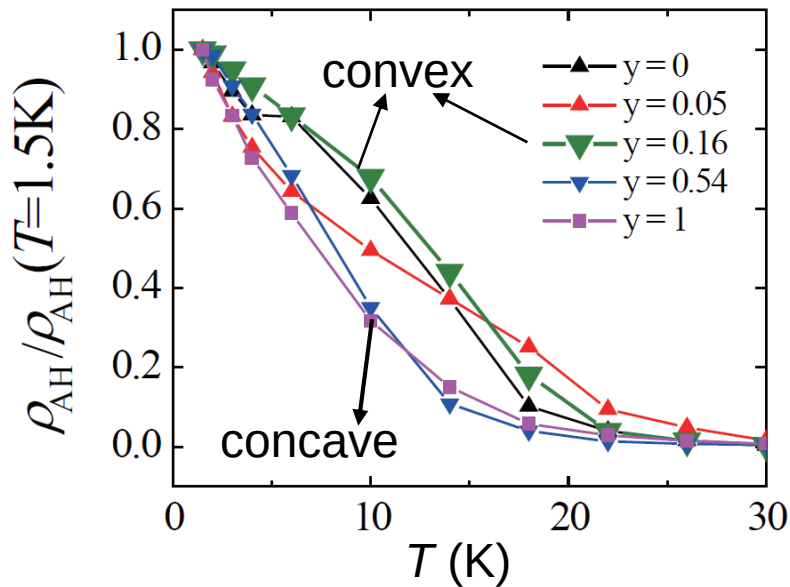


Temperature dependence



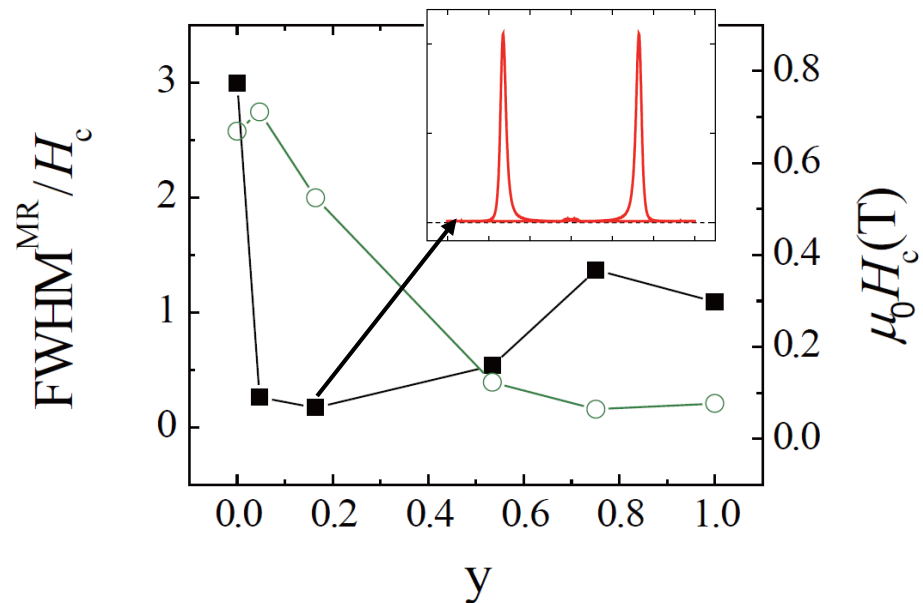
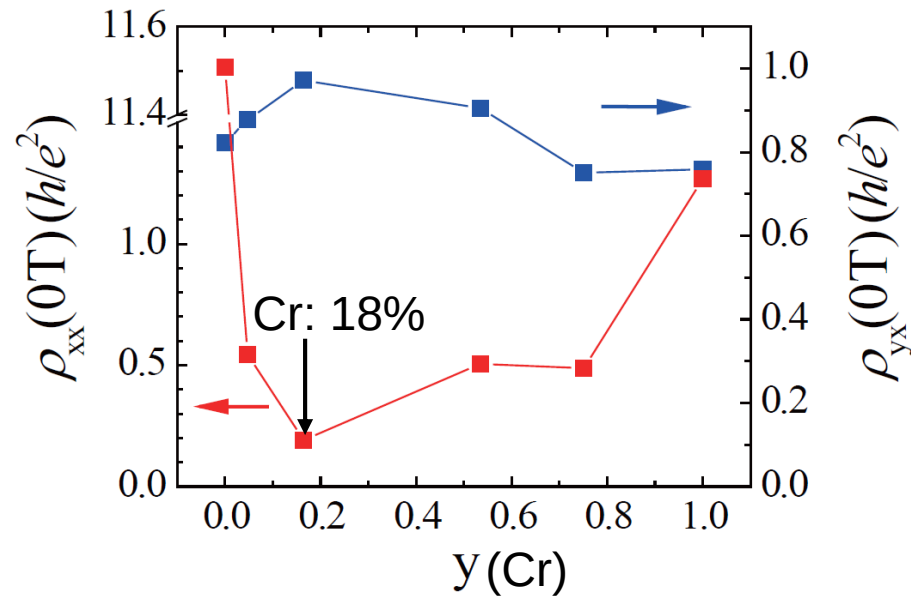
Activation gap ~ 1.4 K

Why co-doped samples do better?



More mean-field-like
 $\rho_{AH}-T$ curve

Improved FM order



sharper magnetization reversal

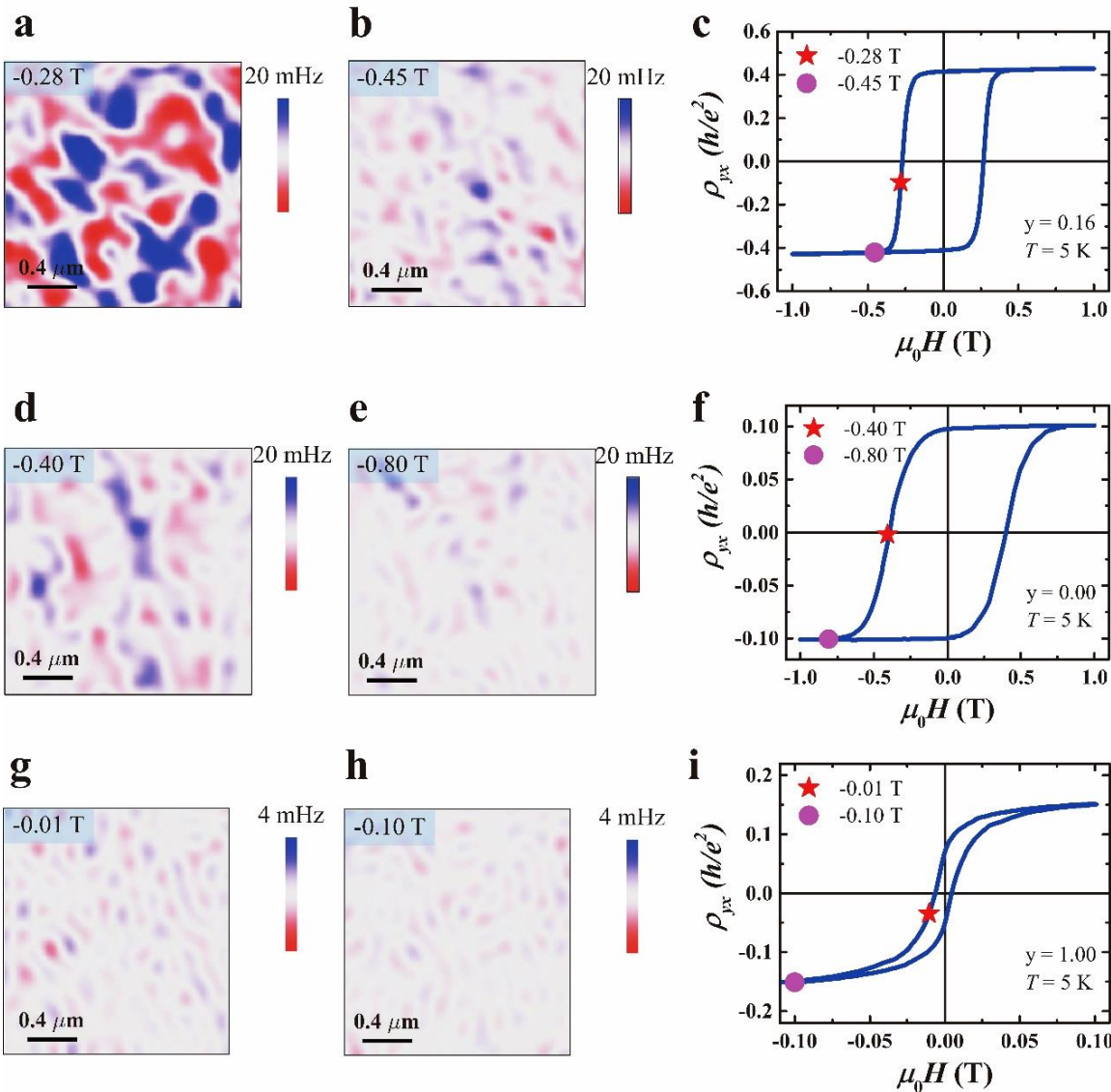
Direct evidence by magnetic force microscopy

Weida Wu, Rutgers
Nat. Phys. (in press)

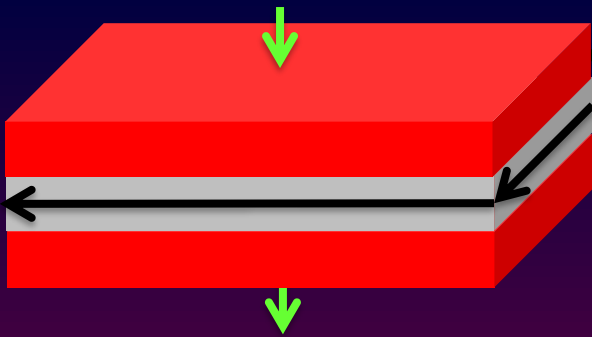
Cr+V co-doped

V-doped

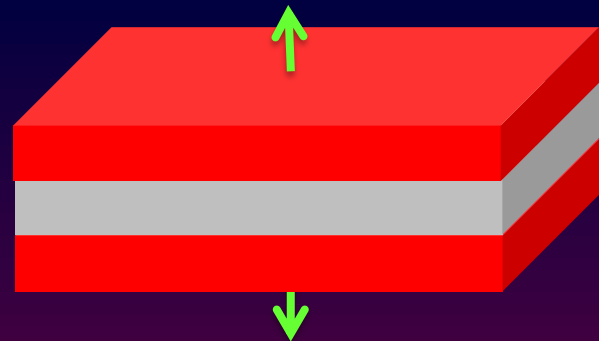
Cr-doped



“Spin valve” based on QAH edge states in Cr+V co-doped $(\text{Bi,Sb})_2\text{Te}_3$ films



QAH insulator



Axion insulator:

Topological magnetoelectric effect



Collinear electric and magnetic fields

“Spin valve” for QAH edge states

Sample
Structure

5 QL
3 QL
5 QL

CVBST (Cr/V: 0.16/0.84—larger coercivity)

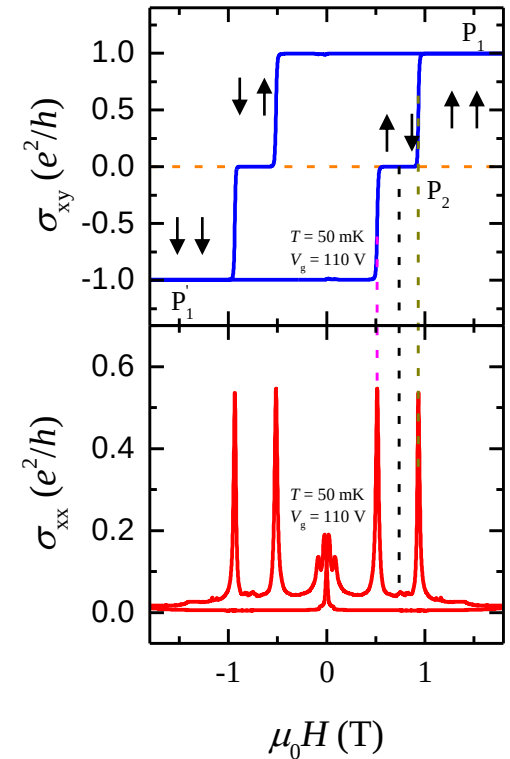
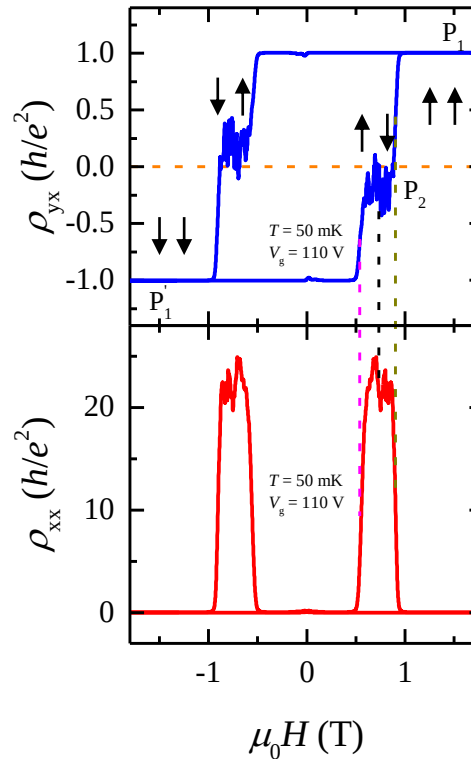
BST (non-magnetic)

CVBST (Cr/V: 0.4/0.6—smaller coercivity)

- When the magnetization directions of the top and bottom layers are parallel, QAH ($\rho_{xx}=0$, $\rho_{xy}=h/e^2$).
- Its longitudinal resistance becomes very large ($\rho_{xx}>20 h/e^2$) when anti-parallel.

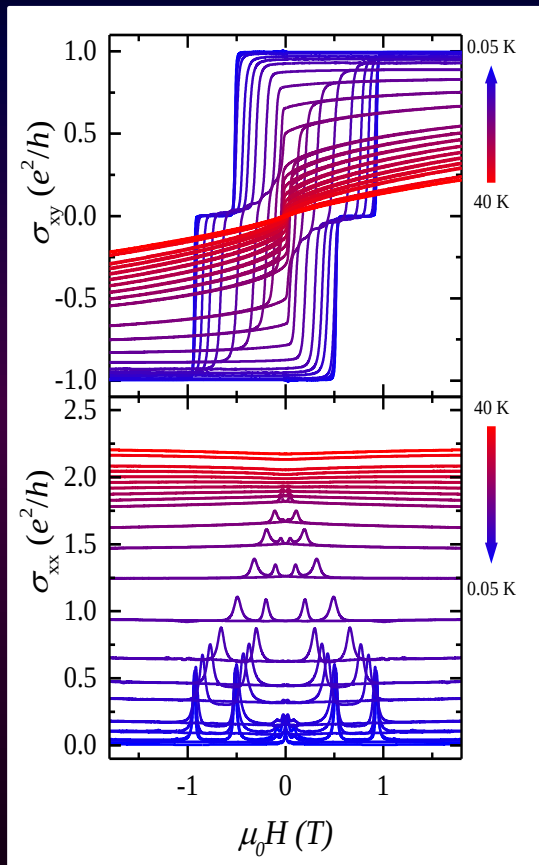


Spin valve

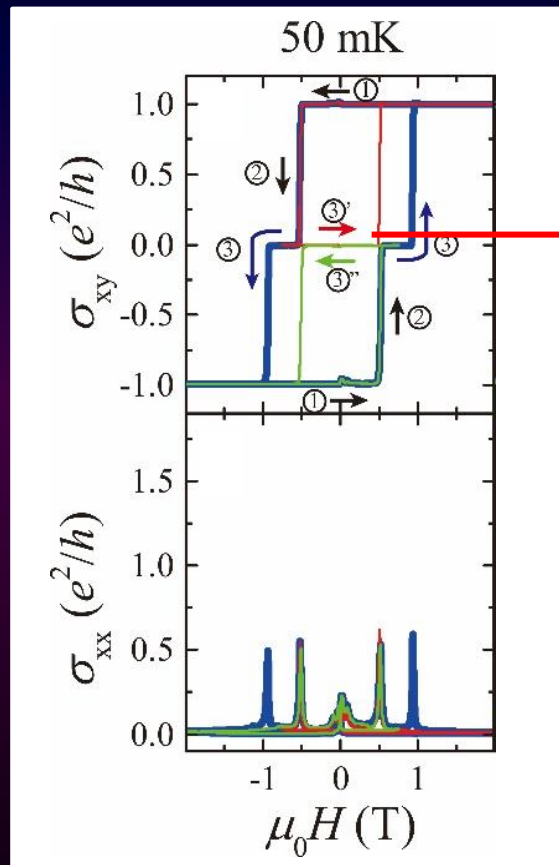


“Spin valve” for QAH edge states

Persistent up to 300 mK

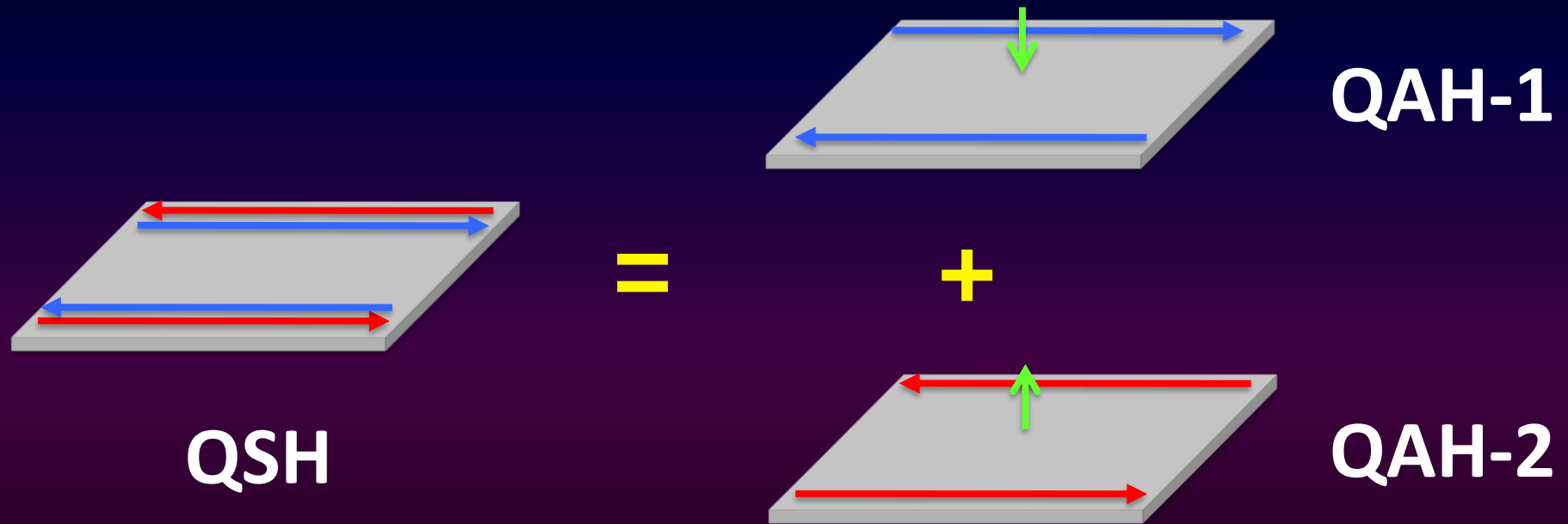


Robust



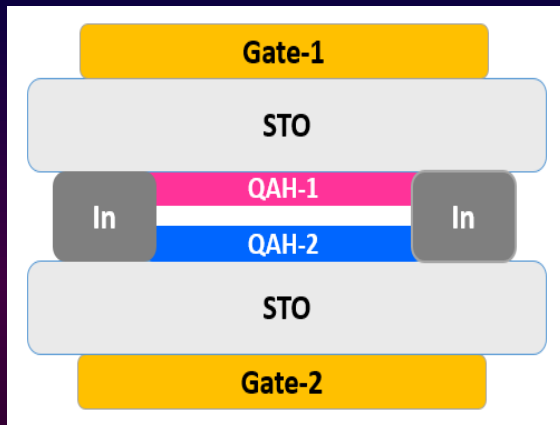
At zero plateau, when we switch off the magnetic field, the system stays at Axion insulator state (stable).

Synthetic Quantum Spin Hall System

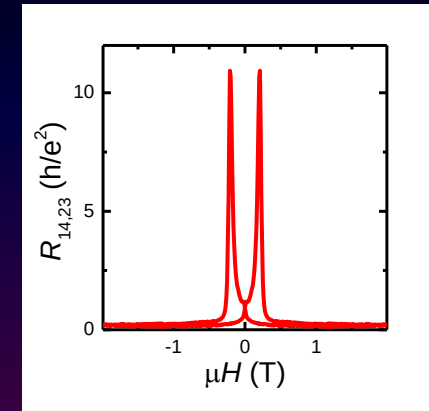
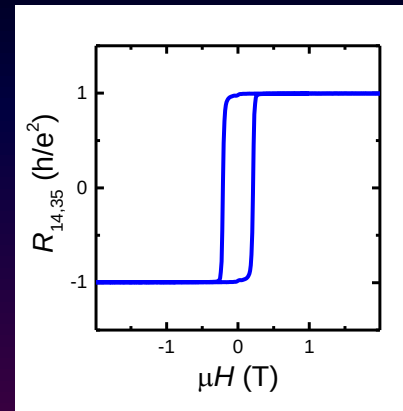


Helical edge states = a pair of counter-propagating QAH chiral edge states

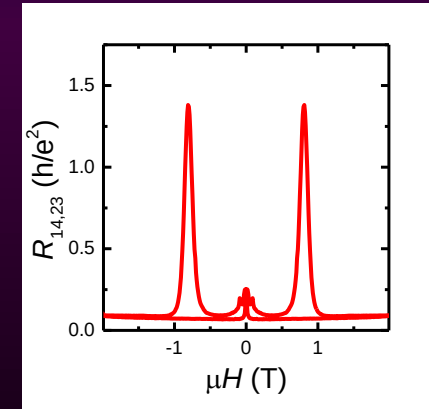
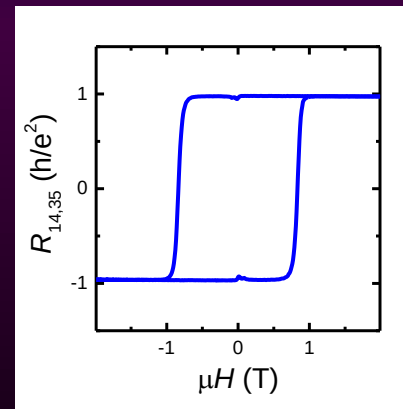
Synthetic Quantum Spin Hall System



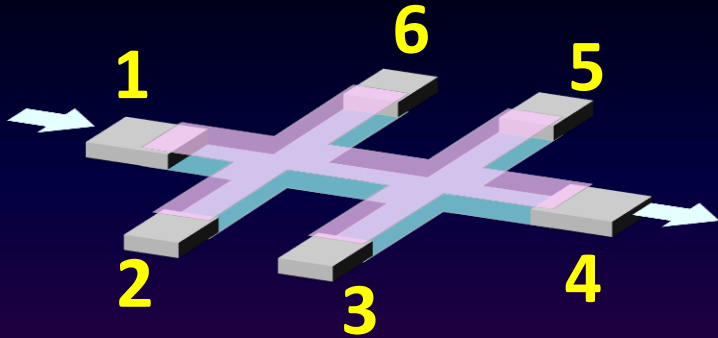
QAH-1
(less V)



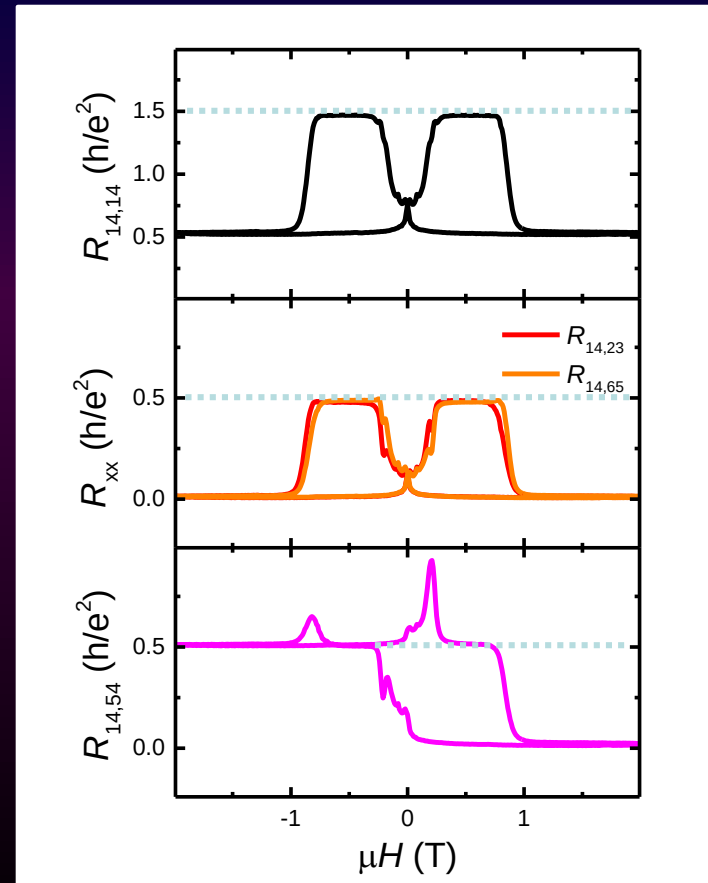
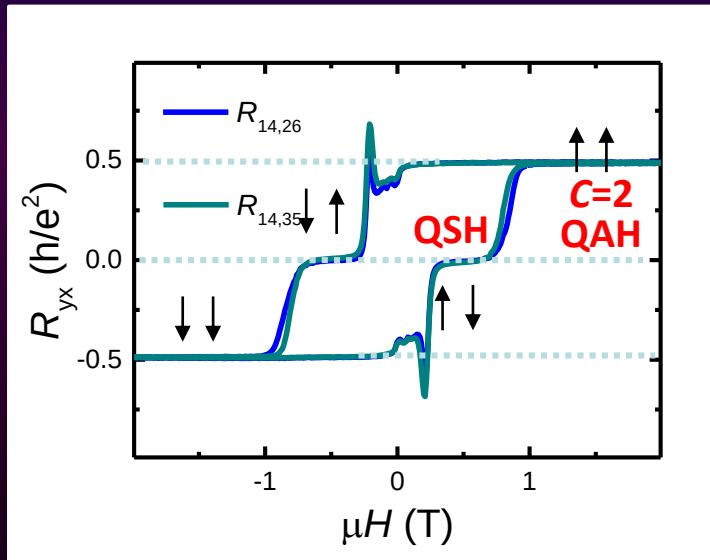
QAH-2
(more V)



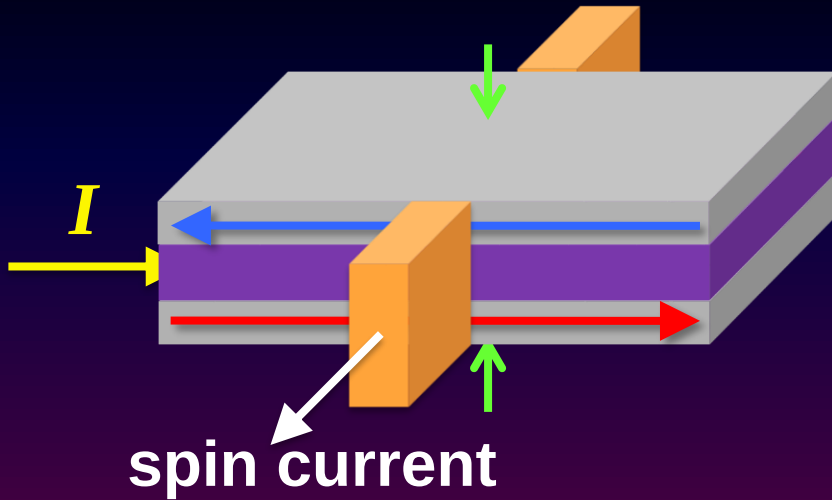
Synthetic Quantum Spin Hall System



- When two QAH sub-systems have the same magnetization direction (strong field), the system becomes a QAH insulator with Chern number 2.
- In the case of opposite magnetization, it becomes a QSH system.



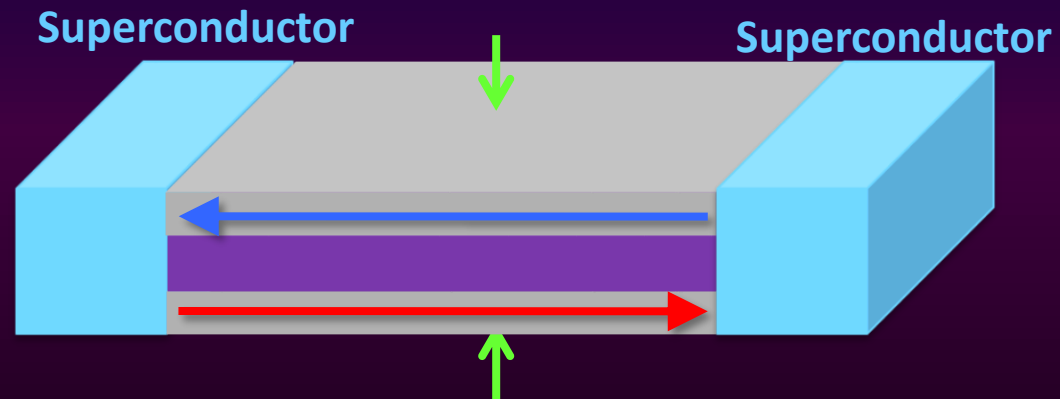
The synthetic QSH system could be useful



Brüne et al., Nat. Phys. 8, 485 (2012)

Q. L. He et al., Science 357, 294 (2017)

However, the two QAH systems are separated too much:
the space is $>$ coherent length

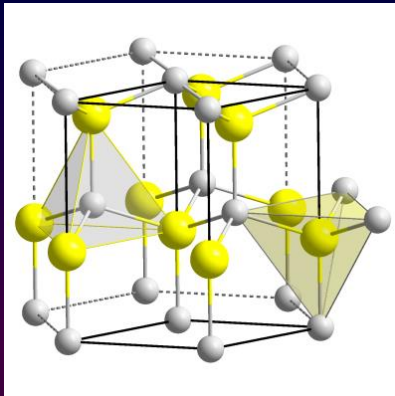


**perfect Andreev reflection
(Majorana mode)**

Knez, Du, Sullivan, Phys. Rev. Lett. 109, 186603 (2012)

Normal insulator spacing layer

CdSe

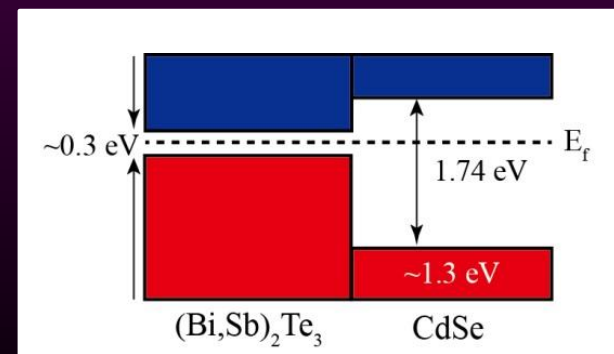
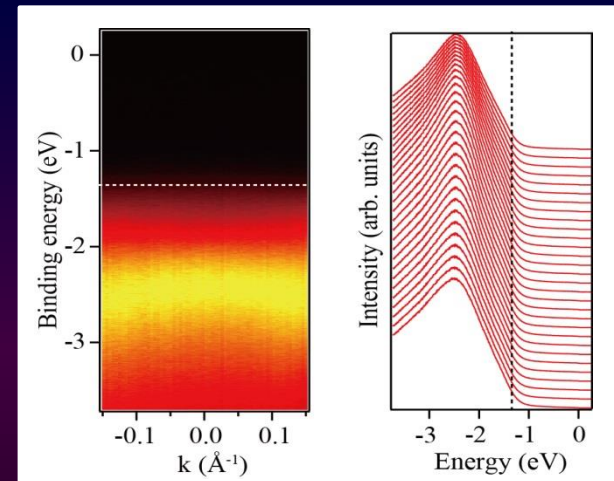


	CdSe	Bi ₂ Te ₃	Sb ₂ Te ₃
Lattice constant (Å)	4.30	4.43	4.26

Bandgap: ~1.74 eV

G. Jiang et al., (unpublished)

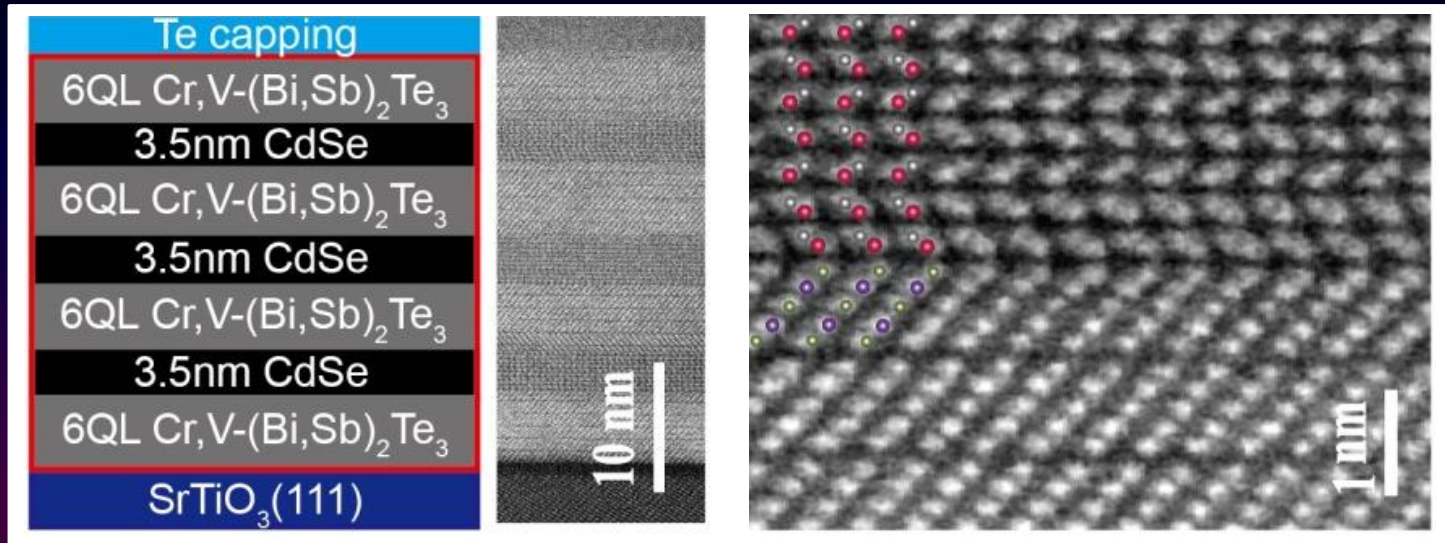
TI-CdSe Band alignment



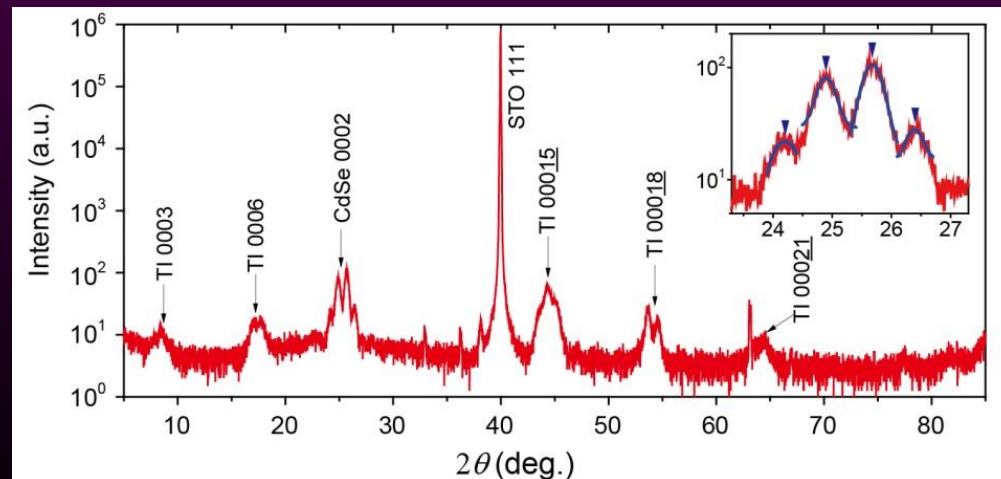
Type-I QW structure

Superlattice of CVBST and CdSe

TEM

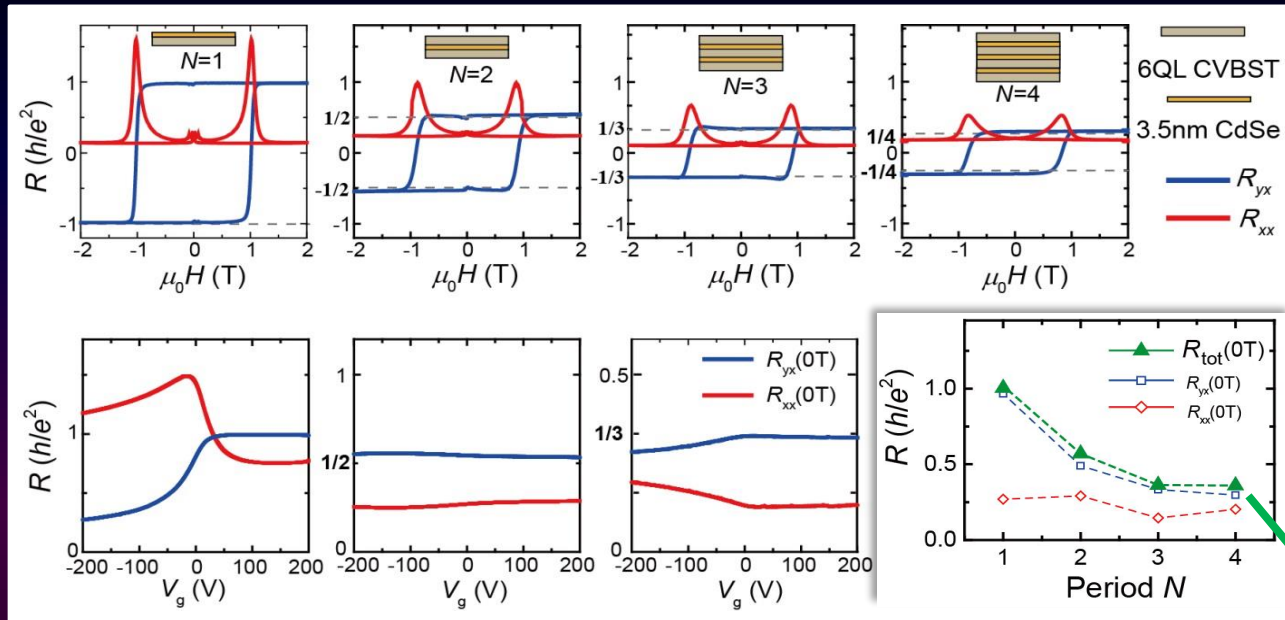


XRD



Super-
lattice
peaks

QAH multilayers



With increasing space layer number (N), the Hall resistance follows h/Ne^2 .

Effective high Chern number QAHE

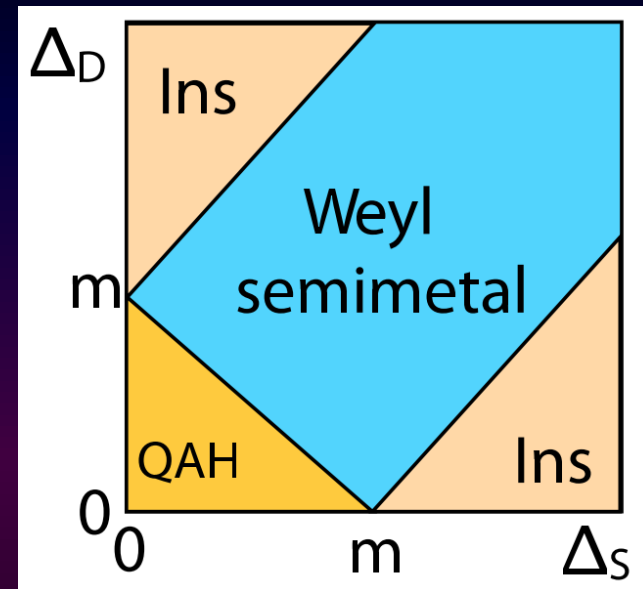
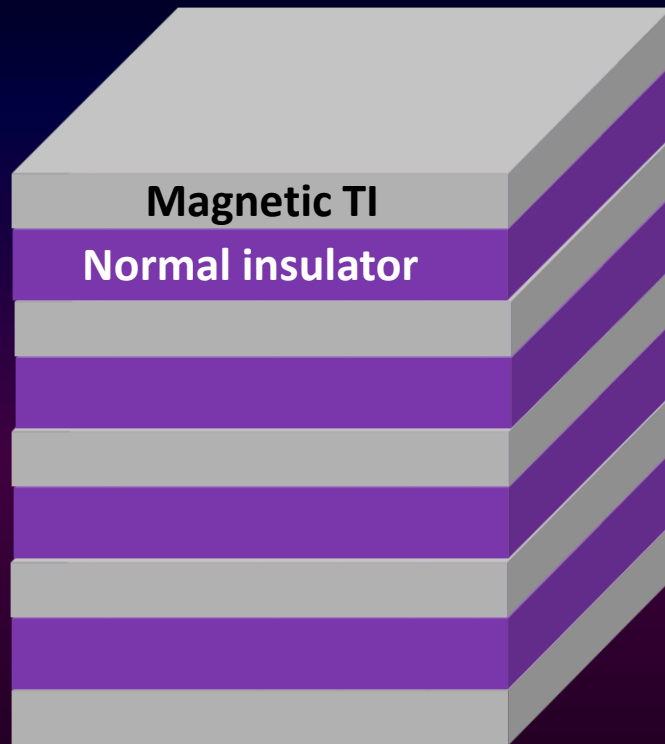
The two-terminal resistance decreases with increasing N



Applications

G. Jiang et al., (unpublished)

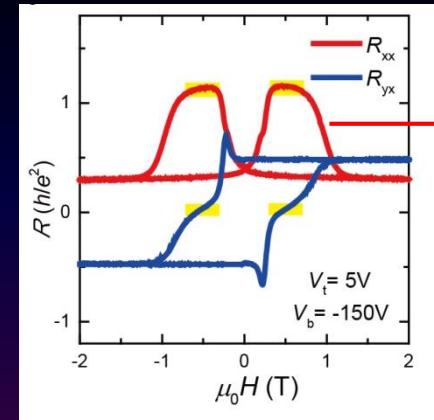
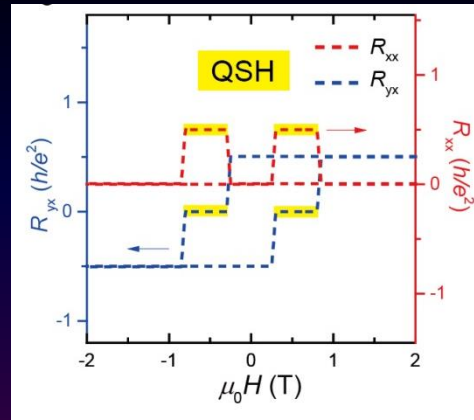
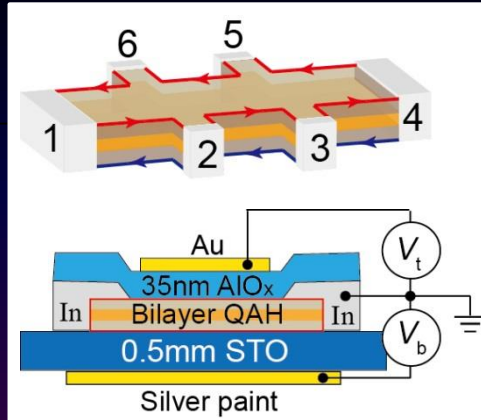
QAH multilayers: magnetic Weyl semimetals



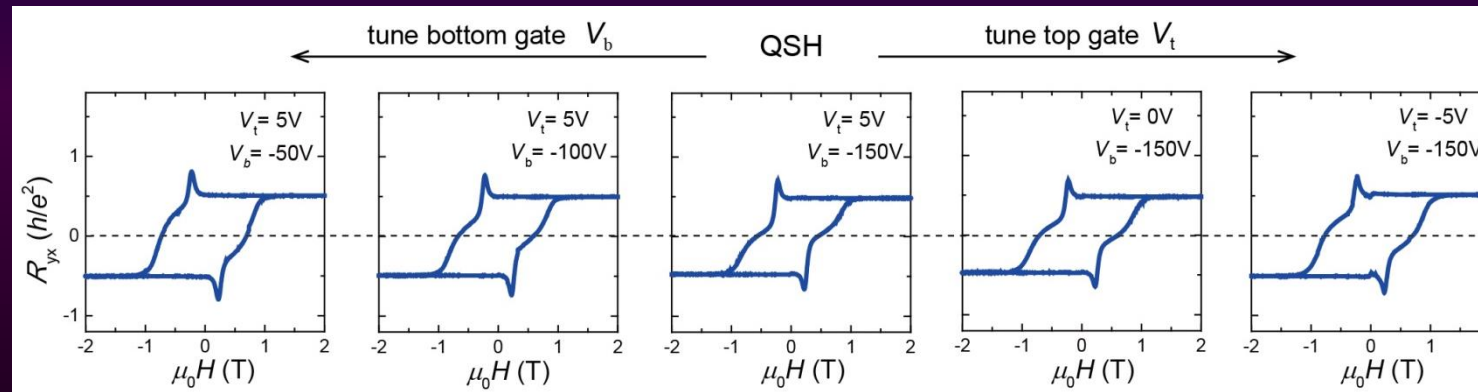
Δ_D : Hybridization between the SSs of two MTI layers

Δ_S : Hybridization between the SSs of a MTI layer

MBE-grown Effective QSH system

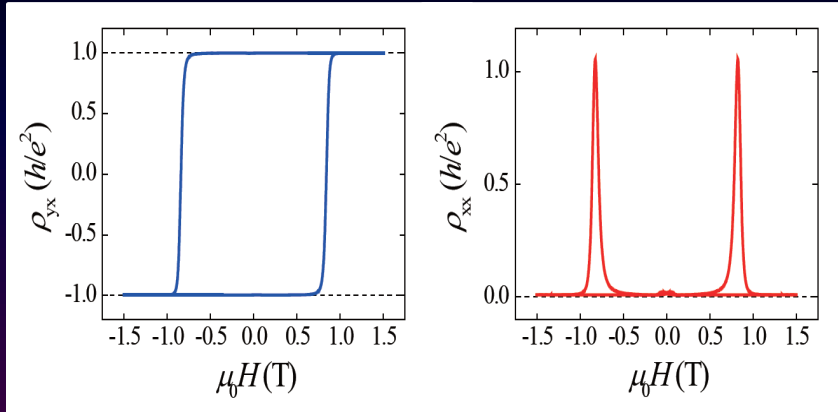


$$R_{xx} > h/e^2$$



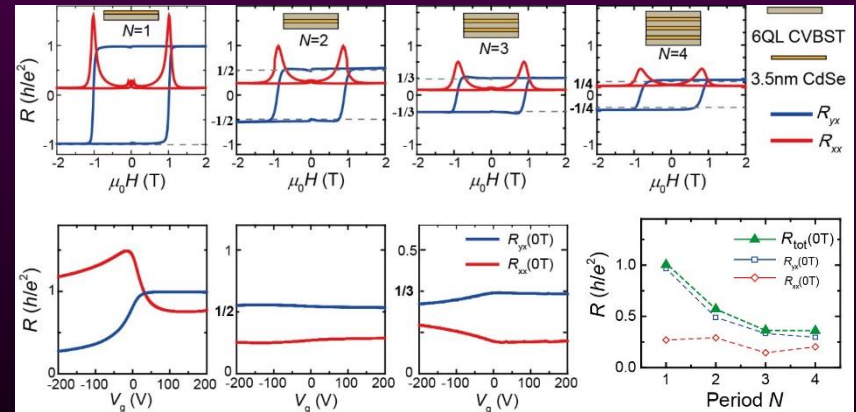
In the “QSH” phase, $R_{xx} > h/2e^2$, which suggests scattering between the two chiral edge channels.

Summary



- Cr+V co-doped $(\text{Bi,Sb})_2\text{Te}_3$ shows improved QAHE and ferromagnetism.

- The improved material enables us to make interesting structures based on QAH systems.



Thank you for your attention !

Synthetic Quantum Spin Hall System

